

Graphene Oxide as Efficient Hole Transporting Material for High-Performance Perovskite Solar Cells with Enhanced Stability

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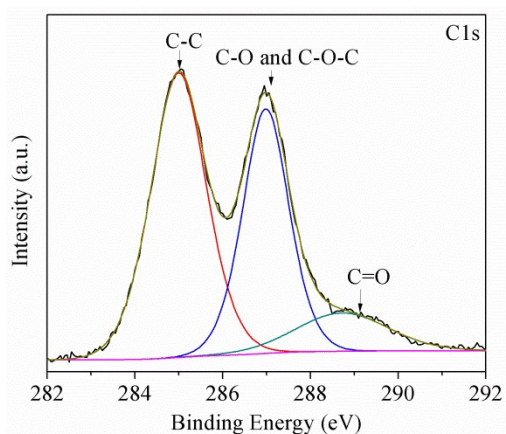


Figure S1. XPS spectra of C 1s for graphene oxide film.